HALOGEN

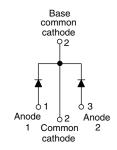
FREE



### Vishay Semiconductors

# Ultrafast Rectifier, 2 x 35 A FRED Pt®





PRODUCT SUMMARY					
Package	TO-218				
I <sub>F(AV)</sub>	2 x 35 A				
$V_R$	400 V				
V <sub>F</sub> at I <sub>F</sub>	1.32 V				
t <sub>rr</sub> typ.	See Recovery table				
T <sub>J</sub> max.	175 °C				
Diode variation	Common cathode				

#### **FEATURES**

- Ultrafast reverse recovery
- · Low forward voltage drop
- Up to 175 °C operating junction temperature
- Common-cathode diodes
- Low leakage current
- Optimized for power conversion: welding and industrial SMPS applications
- Compliant to RoHS Directive 2002/95/EC
- · Designed and qualified for industrial level
- Halogen-free according to IEC 61249-2-21 definition

#### **DESCRIPTION**

The VS-70CRU04PbF integrates two state of the art Vishay Semiconductors ultrafast recovery rectifiers in the common-cathode configuration. The planar structure of the diodes, and the platinum doping life-time control, provide a ultrasoft recovery current shape, together with the best overall performance. ruggedness and reliability characteristics. These devices are thus intended for high frequency applications in which the switching energy is designed not to be predominant portion of the total energy, such as in the output rectification stage of welding machines, SMPS, DC/DC converters. Their extremely optimized stored charge and low recovery current reduce both over-dissipation in the switching elements (and snubbers) and EMI/RFI.

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS	
Cathode to anode voltage	$V_R$		400	V	
Continuous forward current per diode	I <sub>F(AV)</sub>	T <sub>C</sub> = 116 °C	35	^	
Single pulse forward current per diode	I <sub>FSM</sub>	T <sub>C</sub> = 25 °C	300	Α	
Maximum power dissipation per module	$P_D$	T <sub>C</sub> = 100 °C	47	W	
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		- 55 to 175	°C	

<b>ELECTRICAL SPECIFICATIONS PER DIODE</b> (T <sub>J</sub> = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	$V_{BR}, V_{R}$	I <sub>R</sub> = 100 μA	400	-	-	
Forward voltage V <sub>F</sub>		I <sub>F</sub> = 35 A	-	1.11	1.32	V
	V <sub>F</sub>	I <sub>F</sub> = 35 A, T <sub>J</sub> = 125 °C	-	0.98	1.14	
	I <sub>F</sub> = 35 A, T <sub>J</sub> = 175 °C	-	0.92	1.05		
Reverse leakage current I <sub>R</sub>		V <sub>R</sub> = V <sub>R</sub> rated	-	-	100	μΑ
	$T_J = 150  ^{\circ}\text{C},  V_R = V_R  \text{rated}$	-	-	2	mA	
Junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 400 V	-	70	-	pF

## VS-70CRU04PbF





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<b>DYNAMIC RECOVERY CHARACTERISTICS PER DIODE</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Reverse recovery time	t <sub>rr</sub>	$I_F = 1 A, dI_F/dt = 200$	$A/\mu s$ , $V_R = 30 V$	-	32	38	
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	72	-	ns
neverse recovery time		T <sub>J</sub> = 125 °C		-	130	-	
Dook receiver aurrent		T <sub>J</sub> = 25 °C	$I_F = 35 A$ $V_B = 200 V$	-	7.7	-	Α
Peak recovery current I <sub>RRM</sub>	T <sub>J</sub> = 125 °C	$v_R = 200 \text{ V}$ $dI_F/dt = 200 \text{ A/}\mu\text{s}$	-	16.5	-	_ ^	
Reverse recovery charge Q <sub>ri</sub>		T <sub>J</sub> = 25 °C	,	-	0.28	-	
	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	1.08		μC

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Thermal resistance,	oer diode	$R_{thJC}$		-	0.8	1.6	
junction to case bot	th diodes	□thJC		-	0.4	0.8	K/W
Thermal resistance, case to heatsi	nk	R <sub>thCS</sub>	Mounting surface, flat, smooth and greased	-	0.2	-	
Weight				-	4	-	g
vveignt				-	0.13	-	oz.
Mounting torque				1.2 (10)	-	2.4 (20)	N ⋅ m (lbf ⋅ in)
Marking device			Case style TO-218		70CF	RU04	



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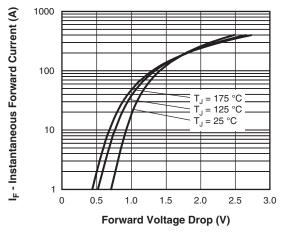


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Diode)

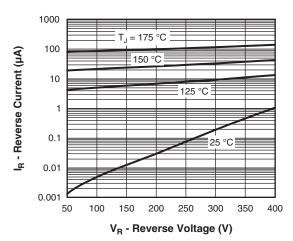


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

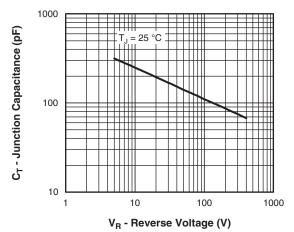


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

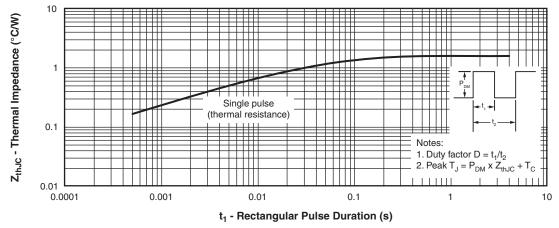


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics (Per Diode)

## Vishay Semiconductors Ultrafast Rectifier, 2 x 35 A FRED Pt®



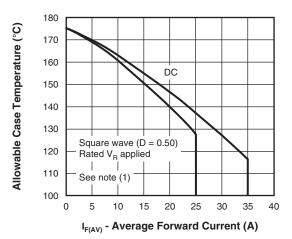


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

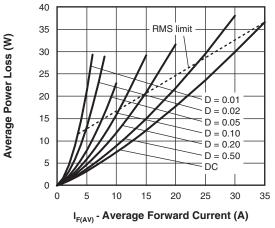


Fig. 6 - Forward Power Loss Characteristics

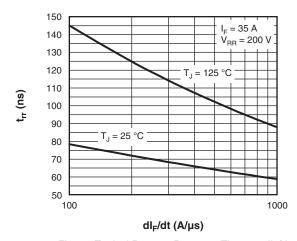


Fig. 7 - Typical Reverse Recovery Time vs.  $dI_F/dt$ 

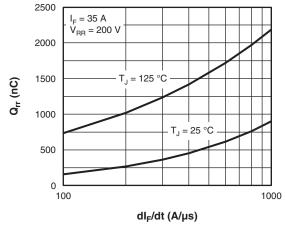


Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

#### Note

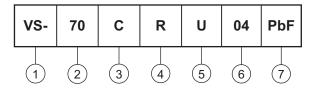
 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{Forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6)}; \\ Pd_{REV} = \text{Inverse power loss} = V_{R1} \times I_R \text{ (1 - D); } I_R \text{ at } V_{R1} = \text{Rated } V_R \\ \end{array}$ 



# Ultrafast Rectifier, 2 x 35 A FRED Pt® Vishay Semiconductors

#### **ORDERING INFORMATION TABLE**

**Device code** 



1 - Vishay Semiconductors product

2 - Current rating (70 = 70 A)

3 - Common cathode

**4** - TO-218

5 - Ultrafast recovery

• Voltage rating (04 = 400 V)

7 - PbF = Lead (Pb)-free

Tube standard pack quantity: 30 pieces

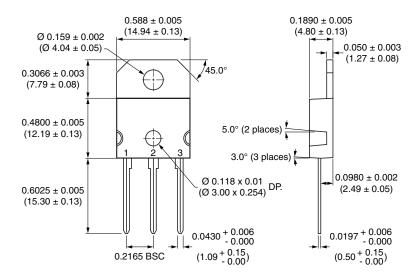
LINKS TO RELATED DOCUMENTS						
Dimensions <u>www.vishay.com/doc?95214</u>						
Part marking information	www.vishay.com/doc?95219					



# Vishay High Power Products

# FRED Pt<sup>TM</sup> TO-218

#### **DIMENSIONS** in millimeters (inches)





## **Legal Disclaimer Notice**

Vishay

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